

30V N-channel MOSFET

Features

- Split Gate Trench Technology
- Low $R_{DS(ON)}$
- Low Gate Charge
- Low Gate Resistance
- 100% UIS Tested

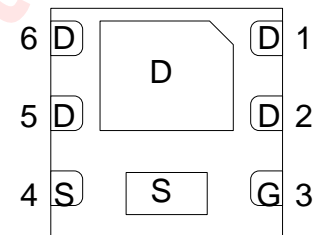
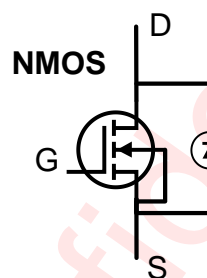
Applications

- Power Switching Application

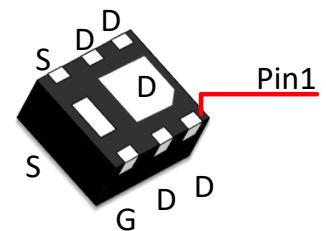
General Description

V_{DS}	$R_{DS(ON)}$ Typ.	I_D
30V	8.5m Ω @ $V_{GS} = 10V$	16A
	12.0m Ω @ $V_{GS} = 4.5V$	

Schematic diagram

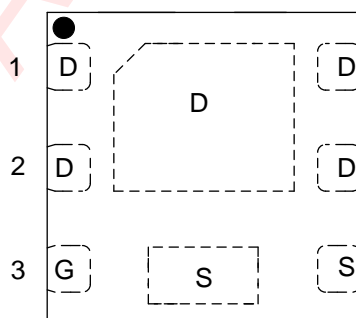


Bottom View

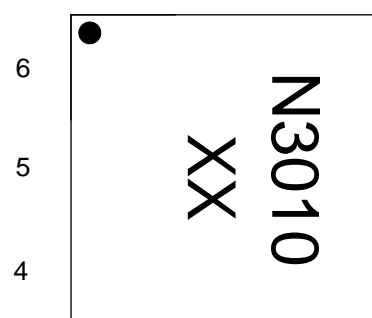


Pin Configuration

AW403058NDNR
(Top View)



AW403058NDNR Marking
(Top View)



N3010 - AW403058NDNR
XX - Date Code

Ordering Information

Part Number	Marking	Package	Environmental Information
AW403058NDNR	N3010	DFN2.0mmX2.0mm-6L	RoHS+HF

Absolute Maximum Ratings

$T_A = T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{DS}	Drain - Source Voltage	30	V
V_{GS}	Gate - Source Voltage	± 20	V
I_D	Continuous Drain Current ($T_A = 25^\circ\text{C}$)(NOTE 1)	16	A
	Continuous Drain Current ($T_A = 55^\circ\text{C}$)(NOTE 1)	12	A
	Continuous Drain Current ($T_A = 100^\circ\text{C}$)(NOTE 1)	10	A
I_{DM}	Pulsed Drain Current(NOTE 2)	64	A
I_{AS}	Single Pulsed Avalanche Current(NOTE 3)	17	A
E_{AS}	Single Pulsed Avalanche Energy(NOTE 3)	72	mJ
P_D	Power Dissipation ($T_A = 25^\circ\text{C}$)(NOTE 4)	3	W
T_J, T_{STG}	Operating and Storage Temperature Range	-55 to +150	$^\circ\text{C}$

Thermal Characteristics

Symbol	Parameter	Value	Units
$R_{\theta JA}$	Thermal Resistance, Junction - to - Ambient Steady State (NOTE 5)	42	$^\circ\text{C/W}$

NOTE1: The maximum current rating is limited by package. And device mounted on a large heatsink.

NOTE2: Pulse Test : Pulse Width $\leq 10\mu\text{s}$, duty cycle $\leq 1\%$.

NOTE3: E_{AS} condition: $V_{DD} = 15\text{V}$, $V_{GS} = 10\text{V}$, $L = 0.5\text{mH}$, $R_G = 25\Omega$ Starting $T_J = 25^\circ\text{C}$.

NOTE4: Pulse Test : Pulse Width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.

NOTE5: The power dissipation P_D is limited by $T_{J(MAX)} = 150^\circ\text{C}$. And device mounted on a large heatsink.

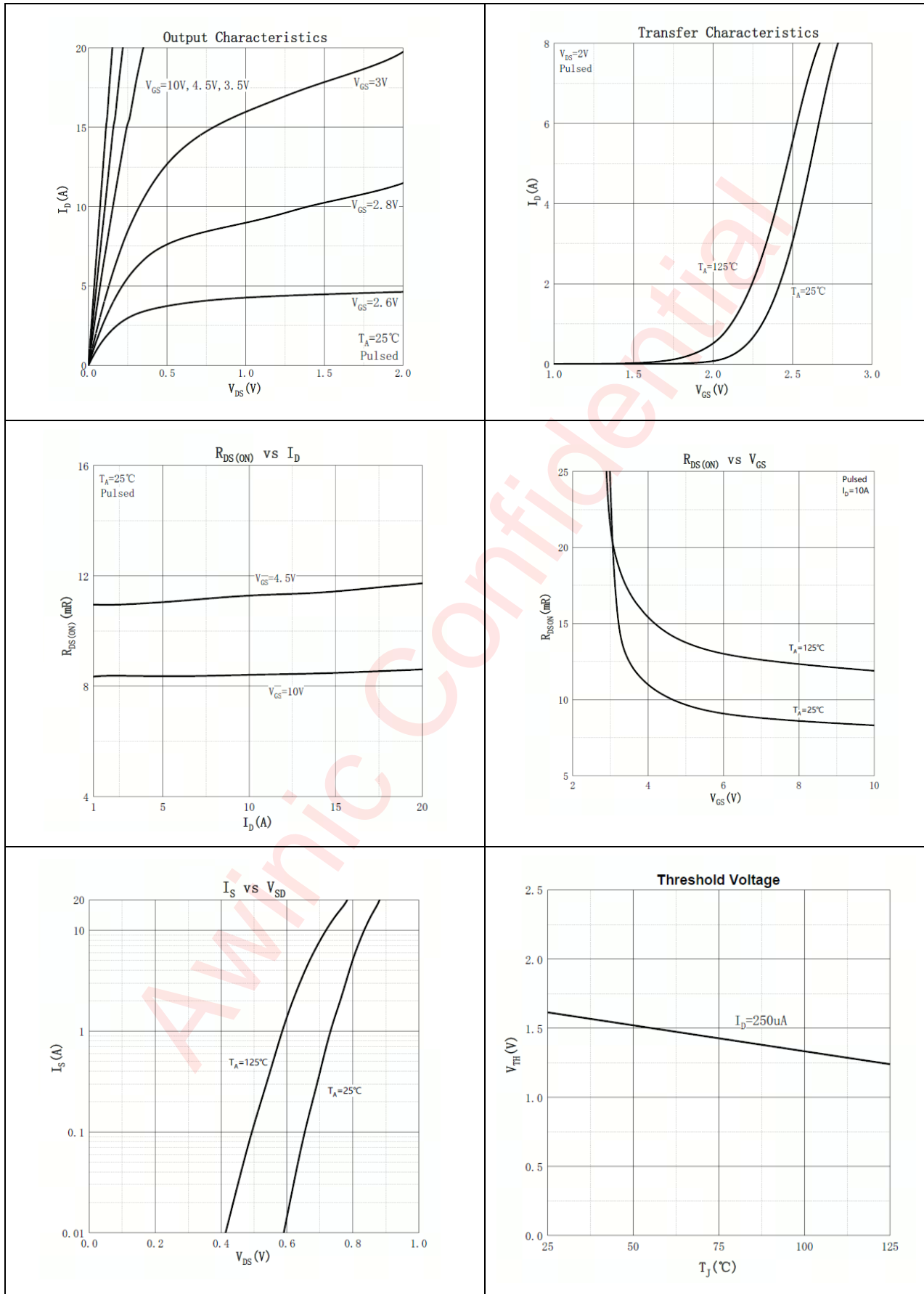
NOTE6: Device mounted on 1in^2 FR-4 board with 2oz. Copper, in a still air environment with $T_A = 25^\circ\text{C}$.

Electrical Characteristics

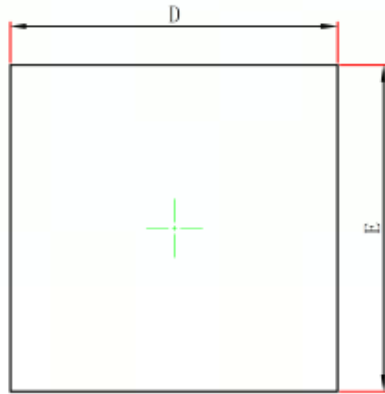
$T_A=T_J = 25^{\circ}\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
Static Characteristics						
BV_{DSS}	Drain - Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	30			V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24V, V_{GS} = 0V$			1	μA
I_{GSS}	Gate Leakage Current	$V_{GS} = \pm 20V, V_{DS} = 0V$			± 100	nA
$V_{GS(TH)}$	Gate Threshold Voltage ^(NOTE 3)	$V_{DS} = V_{GS}, I_D = 250\mu A$	1.0	1.5	3.0	V
$R_{DS(ON)}$	Drain - Source On-state Resistance ^(NOTE 3)	$V_{GS} = 10V, I_D = 5A$		8.5	12.0	m Ω
		$V_{GS} = 4.5V, I_D = 5A$		12.0	18.0	
Dynamic Characteristics						
C_{iss}	Input Capacitance	$V_{DS} = 15V, V_{GS} = 0V,$ $f = 1\text{ MHz}$		1265		pF
C_{oss}	Output Capacitance			144		pF
C_{rss}	Reverse Transfer Capacitance			134		pF
R_g	Gate Resistance	$V_{DS} = 0V, V_{GS} = 0V,$ $f = 1\text{ MHz}$		1.5		Ω
Switching Characteristics						
Q_g	Total Gate Charge	$V_{DS} = 15V, I_D = 10A,$ $V_{GS} = 10V$		12		nC
Q_{gs}	Gate - Source Charge			4.7		nC
Q_{gd}	Gate - Drain Charge			3.4		nC
$t_{d(on)}$	Turn On Delay Time	$V_{DD} = 15V, V_{GS} = 10V,$ $R_L = 1.5\Omega, R_G = 3\Omega$		6.8		ns
t_r	Rise Time			12		
$t_{d(off)}$	Turn Off Delay Time			22		
t_f	Fall Time			7		
Source- Drain Diode Characteristics and Maximum Ratings						
V_{SD}	Diode Forward Voltage ^(NOTE 3)	$V_{GS} = 0V, I_S = 5A$			1.2	V

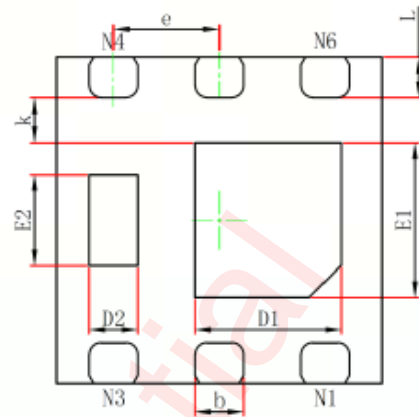
Electrical Characteristics Diagrams



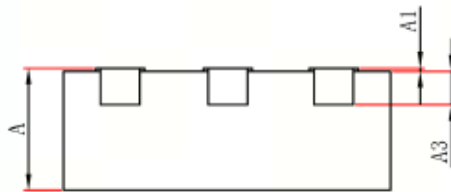
Package Description



TOP VIEW



BOTTOM VIEW



SIDE VIEW

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.700	0.800	0.028	0.031
A1	0	0.050	0	0.002
A3	2.03REF		0.008REF	
D	1.900	2.100	0.075	0.083
E	1.900	2.100	0.075	0.083
D1	0.800	1.000	0.031	0.039
E1	0.850	1.050	0.033	0.041
D2	0.200	0.400	0.008	0.016
E2	0.460	0.660	0.018	0.026
k	0.200MIN		0.008MIN	
b	0.250	0.350	0.010	0.014
e	0.65BSC		0.026TYP	
L	0.174	0.326	0.007	0.013

Revision History

Version	Date	Change Record
V1.0	Nov. 2023	Official released

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